

## TC74ACT153P, TC74ACT153F, TC74ACT153FN

### Dual 4-Channel Multiplexer

The TC74ACT153 is an advanced high speed CMOS DUAL 4-CHANNEL MULTIPLEXERS fabricated with silicon gate and double-layer metal wiring C<sup>2</sup>MOS technology.

They achieve the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipations.

This device may be used as a level converter for interfacing TTL or NMOS to High Speed CMOS. The inputs are compatible with TTL, NMOS and CMOS output voltage levels.

Each of these data (1C0-1C3, 2C0-2C3) is selected by the two address inputs A and B.

Separate strobe inputs ( $1\bar{G}$ ,  $2\bar{G}$ ) are provided for each of the two four-line sections.

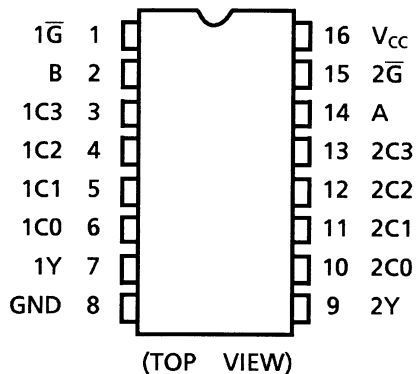
The strobe input can be used to inhibit the data output; the output is fixed in low level unconditionally.

All inputs are equipped with protection circuits against static discharge or transient excess voltage.

### Features

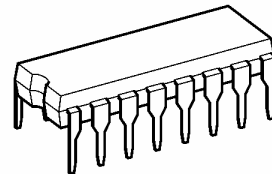
- High speed:  $t_{pd} = 5.4 \text{ ns (typ.)}$  at  $V_{CC} = 5 \text{ V}$
- Low power dissipation:  $I_{CC} = 8 \mu\text{A (max)}$  at  $T_a = 25^\circ\text{C}$
- Compatible with TTL outputs:  $V_{IL} = 0.8 \text{ V (max)}$   
 $V_{IH} = 2.0 \text{ V (min)}$
- Symmetrical output impedance:  $|I_{OH}| = I_{OL} = 24 \text{ mA (min)}$   
Capability of driving  $50 \Omega$  transmission lines.
- Balanced propagation delays:  $t_{pLH} \approx t_{pHL}$
- Pin and function compatible with 74F153

### Pin Assignment



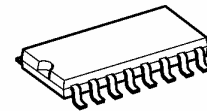
Note: xxxFN (JEDEC SOP) is not available in Japan.

TC74ACT153P

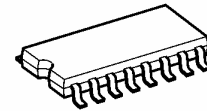


DIP16-P-300-2.54A

TC74ACT153F

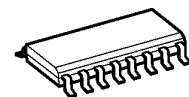


SOP16-P-300-1.27A



SOP16-P-300-1.27

TC74ACT153FN

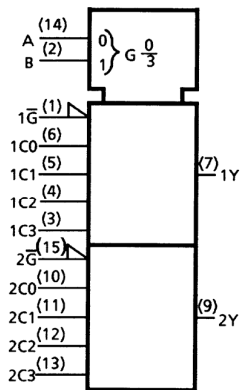


SOL16-P-150-1.27

### Weight

DIP16-P-300-2.54A	: 1.00 g (typ.)
SOP16-P-300-1.27A	: 0.18 g (typ.)
SOP16-P-300-1.27	: 0.18 g (typ.)
SOL16-P-150-1.27	: 0.13 g (typ.)

IEC Logic Symbol

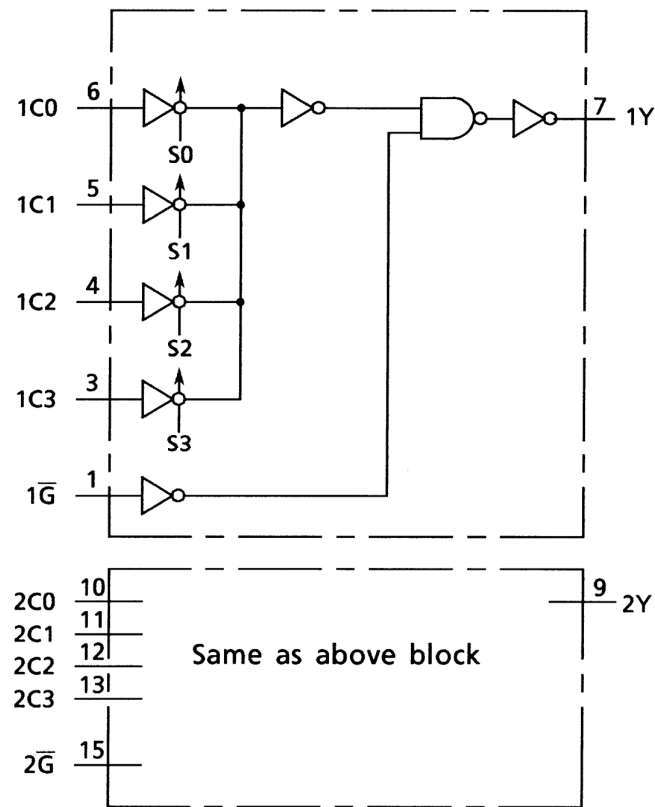
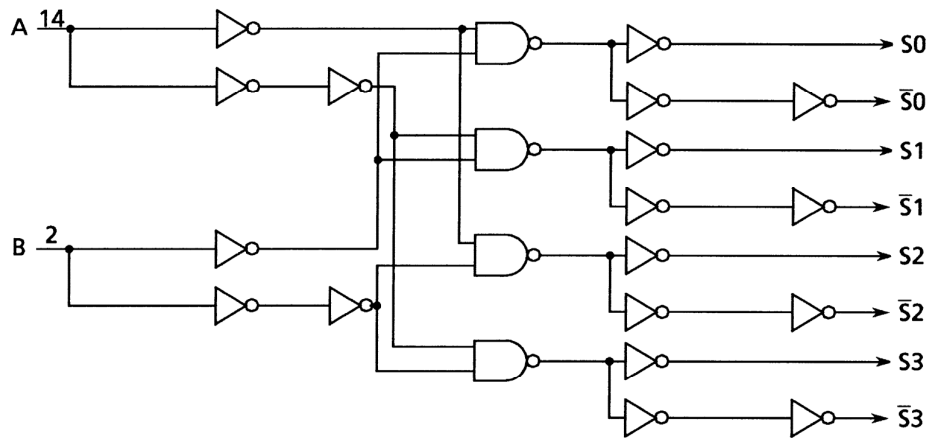


Truth Table

Select Inputs		Data Inputs				Strobe	Output
B	A	C0	C1	C2	C3	$\overline{G}$	Y
X	X	X	X	X	X	H	L
L	L	L	X	X	X	L	L
L	L	H	X	X	X	L	H
L	H	X	L	X	X	L	L
L	H	X	H	X	X	L	H
H	L	X	X	L	X	L	L
H	L	X	X	H	X	L	H
H	H	X	X	X	L	L	L
H	H	X	X	X	H	L	H

X: Don't care

## System Diagram



**Absolute Maximum Ratings (Note 1)**

Characteristics	Symbol	Rating	Unit
Supply voltage range	$V_{CC}$	-0.5 to 7.0	V
DC input voltage	$V_{IN}$	-0.5 to $V_{CC} + 0.5$	V
DC output voltage	$V_{OUT}$	-0.5 to $V_{CC} + 0.5$	V
Input diode current	$I_{IK}$	$\pm 20$	mA
Output diode current	$I_{OK}$	$\pm 50$	mA
DC output current	$I_{OUT}$	$\pm 50$	mA
DC $V_{CC}$ /ground current	$I_{CC}$	$\pm 100$	mA
Power dissipation	$P_D$	500 (DIP) (Note 2)/180 (SOP)	mW
Storage temperature	$T_{stg}$	-65 to 150	°C

Note1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Note2: 500 mW in the range of  $T_a = -40$  to  $65^\circ\text{C}$ . From  $T_a = 65$  to  $85^\circ\text{C}$  a derating factor of  $-10 \text{ mW}/^\circ\text{C}$  should be applied up to 300 mW.

**Recommended Operating Conditions (Note)**

Characteristics	Symbol	Rating	Unit
Supply voltage	$V_{CC}$	4.5 to 5.5	V
Input voltage	$V_{IN}$	0 to $V_{CC}$	V
Output voltage	$V_{OUT}$	0 to $V_{CC}$	V
Operating temperature	$T_{opr}$	-40 to 85	°C
Input rise and fall time	$dt/dV$	0 to 10	ns/V

Note: The recommended operating conditions are required to ensure the normal operation of the device. Unused inputs must be tied to either  $V_{CC}$  or GND.

## Electrical Characteristics

## DC Characteristics

Characteristics	Symbol	Test Condition		Ta = 25°C			Ta = -40 to 85°C		Unit	
				V <sub>CC</sub> (V)	Min	Typ.	Max	Min		Max
High-level input voltage	V <sub>IH</sub>	—		4.5 to 5.5	2.0	—	—	2.0	—	V
Low-level input voltage	V <sub>IL</sub>	—		4.5 to 5.5	—	—	0.8	—	0.8	V
High-level output voltage	V <sub>OH</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OH</sub> = -50 μA	4.5	4.4	4.5	—	4.4	—	V
			I <sub>OH</sub> = -24 mA	4.5	3.94	—	—	3.80	—	
			I <sub>OH</sub> = -75 mA (Note)	5.5	—	—	—	3.85	—	
Low-level output voltage	V <sub>OL</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OL</sub> = 50 μA	4.5	—	0.0	0.1	—	0.1	V
			I <sub>OL</sub> = 24 mA	4.5	—	—	0.36	—	0.44	
			I <sub>OL</sub> = 75 mA (Note)	5.5	—	—	—	—	1.65	
Input leakage current	I <sub>IN</sub>	V <sub>IN</sub> = V <sub>CC</sub> or GND		5.5	—	—	±0.1	—	±1.0	μA
Quiescent supply current	I <sub>CC</sub>	V <sub>IN</sub> = V <sub>CC</sub> or GND		5.5	—	—	8.0	—	80.0	μA
	I <sub>C</sub>	Per input: V <sub>IN</sub> = 3.4 V Other input: V <sub>CC</sub> or GND		5.5	—	—	1.35	—	1.5	mA

Note: This spec indicates the capability of driving 50 Ω transmission lines.

One output should be tested at a time for a 10 ms maximum duration.

AC Characteristics (C<sub>L</sub> = 50 pF, R<sub>L</sub> = 500 Ω, input: t<sub>r</sub> = t<sub>f</sub> = 3 ns)

Characteristics	Symbol	Test Condition		Ta = 25°C			Ta = -40 to 85°C		Unit
			V <sub>CC</sub> (V)	Min	Typ.	Max	Min	Max	
Propagation delay time (Cn-Y)	t <sub>pLH</sub> t <sub>pHL</sub>	—	5.0 ± 0.5	—	6.1	9.7	1.0	11.0	ns
Propagation delay time (A, B-Y)	t <sub>pLH</sub> t <sub>pHL</sub>	—	5.0 ± 0.5	—	7.8	11.8	1.0	13.5	ns
Propagation delay time ( $\bar{G}$ -Y)	t <sub>pLH</sub> t <sub>pHL</sub>	—	5.0 ± 0.5	—	5.6	9.7	1.0	11.0	ns
Input capacitance	C <sub>IN</sub>	—		—	5	10	—	10	pF
Power dissipation capacitance	CPD (Note)	—		—	47	—	—	—	pF

Note: C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

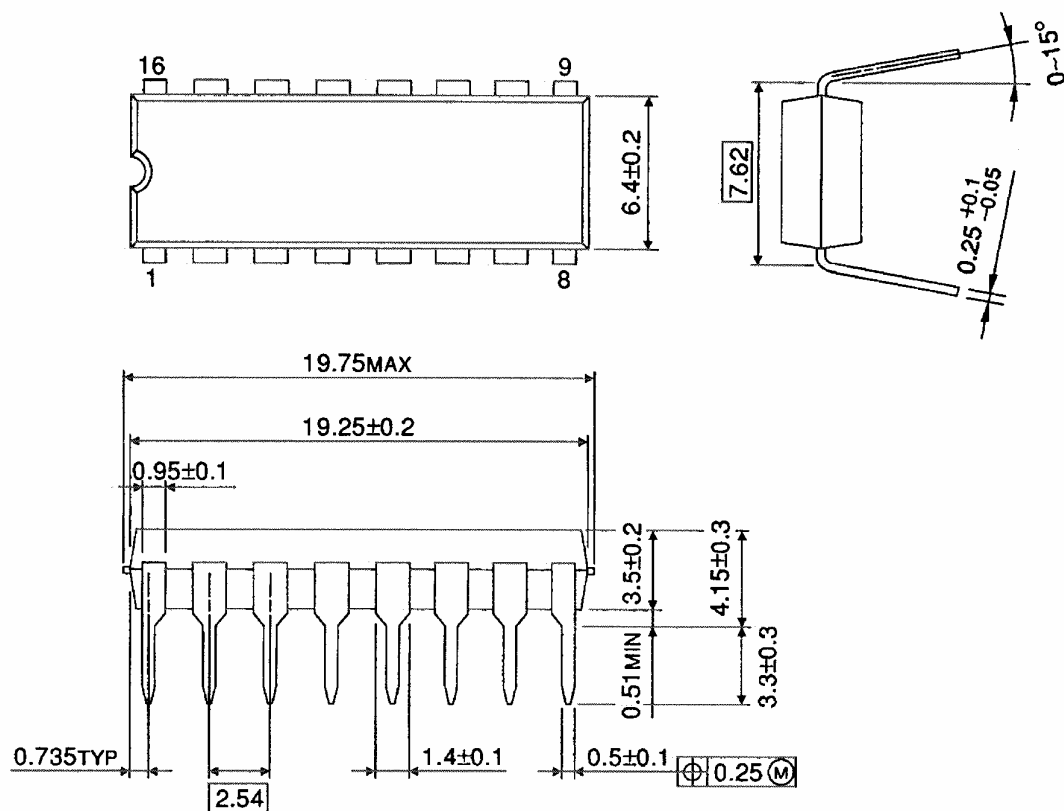
Average operating current can be obtained by the equation:

$$I_{CC}(\text{opr}) = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$$

## Package Dimensions

DIP16-P-300-2.54A

Unit : mm

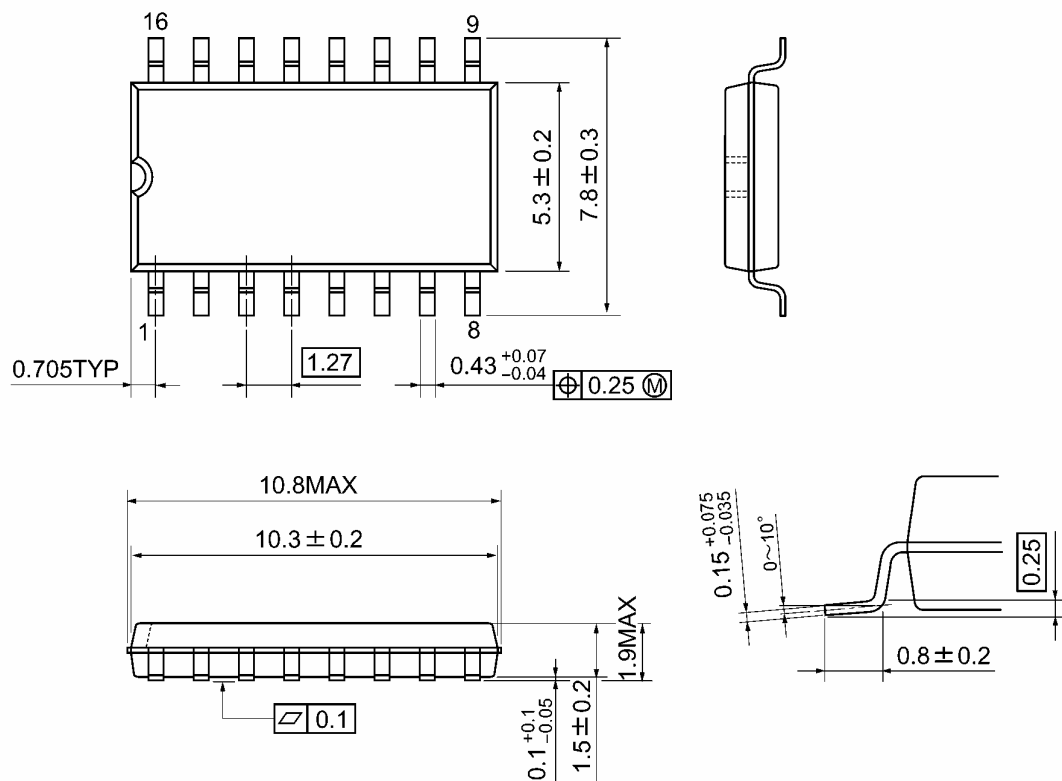


Weight: 1.00 g (typ.)

## Package Dimensions

SOP16-P-300-1.27A

Unit: mm

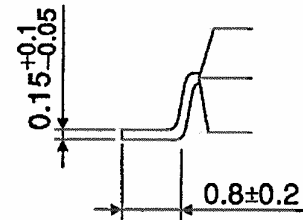
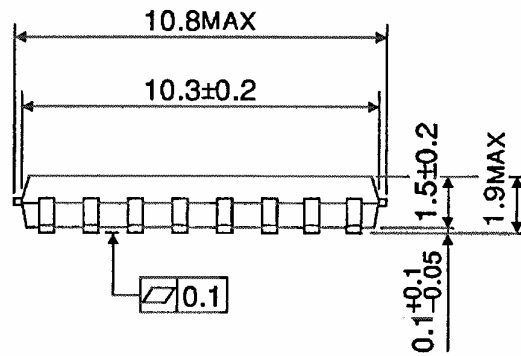
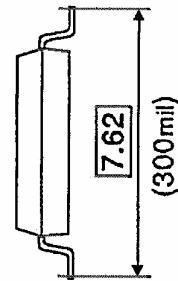
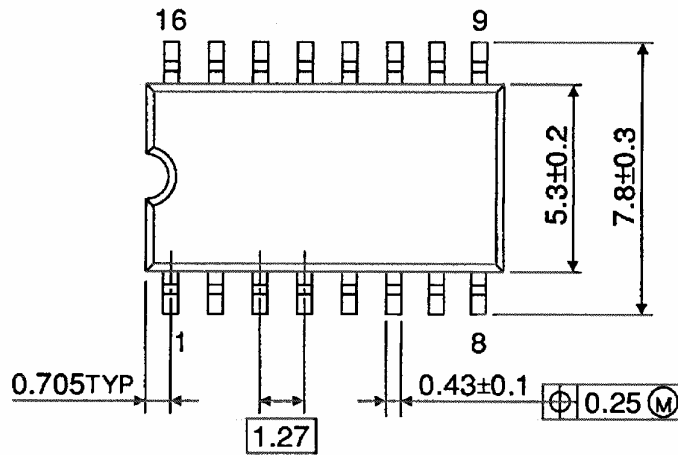


Weight: 0.18 g (typ.)

## Package Dimensions

SOP16-P-300-1.27

Unit : mm



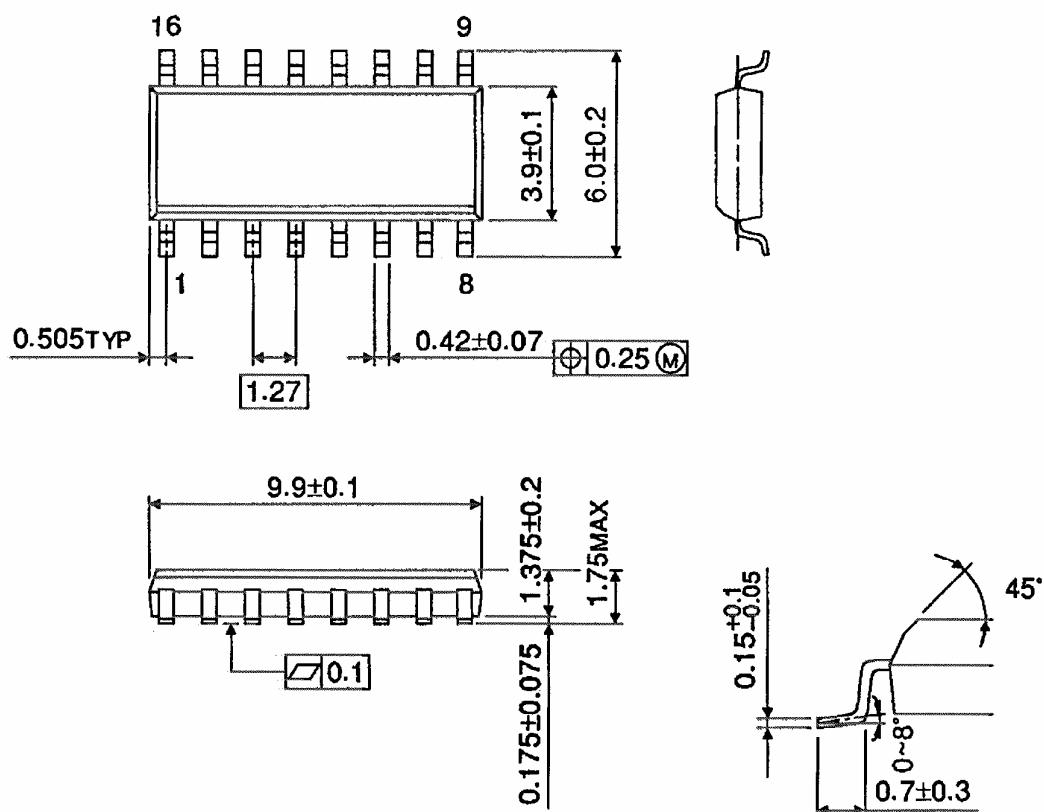
Weight: 0.18 g (typ.)



## Package Dimensions (Note)

SOL16-P-150-1.27

Unit : mm



Note: This package is not available in Japan.

Weight: 0.13 g (typ.)

**Note: Lead (Pb)-Free Packages****DIP16-P-300-2.54A SOP16-P-300-1.27A SOL16-P-150-1.27****RESTRICTIONS ON PRODUCT USE**

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